



# **General Purpose Rectifier**



#### **Features**

- High efficiency
- High current capability
- High reliability
- High surge current capability
- Low power loss
- Glass passivated chip junction
- Solder dip 275 °C max. 7 s, per JESD 22-B106

#### **Typical Applications**

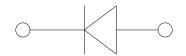
For use in general purpose rectification of power supplies, inverters, converters, and freewheeling diodes for consumer, and telecommunication.

#### **Mechanical Data**

• Package:DO-201AD(DO-27)

Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant

- **Terminals**: Tin plated leads, solderable per J-STD-002 and JESD22-B102
- Polarity:Color band denotes cathode end



#### ■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	1N5400G	1N5401G	1N5402G	1N5404G	1N5406G	1N5407G	1N5408G	
Device marking code			1N5400G	1N5401G	1N5402G	1N5404G	1N5406G	1N5407G	1N5408G	
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	٧	50	100	200	400	600	800	1000	
Maximum RMS Voltage	V <sub>RMS</sub>	V	35	70	140	280	420	560	700	
Maximum DC blocking Voltage	$V_{DC}$	V	50	100	200	400	600	800	1000	
Average Forward Current @60Hz sine wave, Resistance load, Ta =70°C	I <sub>F(AV)</sub>	Α	3.0							
Forward Surge Current (Non-repetitive) @60Hz Half-sine wave,1 cycle, Tj=25℃	200									
Forward Surge Current (Non-repetitive) @1ms, square wave, 1 cycle, Tj=25℃	IFSM	Α	400							
Current squared time @1ms≤t8.3≤ms Tj=25℃,Rating of per diode	l²t	A <sup>2</sup> s	166							
Typical junction capacitance @Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C	Cj	pF	40							
Storage Temperature	T <sub>stg</sub>	°	-55 ~ <b>+</b> 150							
Junction Temperature	Tj	°C	-55 ~ +150							

#### **■Electrical Characteristics** (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	1N5400G	1N5401G	1N5402G	1N5404G	1N5406G	1N5407G	1N5408G
Maximum instantaneous forward voltage drop per diode	VF	٧	I <sub>F</sub> =3.0A				1.0			
Maximum DC reverse current at rated DC blocking voltage	IR		T <sub>j</sub> =25°C	2.5						
per diode	ır.	μΑ	T <sub>j</sub> =125°C				100			

## 1N5400G THRU 1N5408G

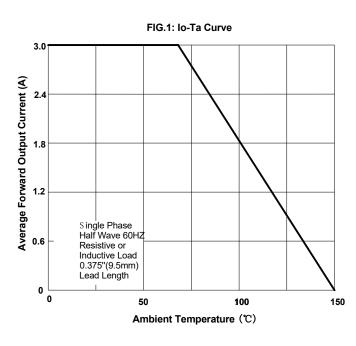
## ■Thermal Characteristics (T<sub>a</sub>=25°C Unless otherwise specified)

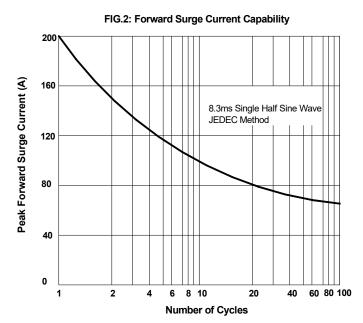
PARAMETER	SYMBOL	UNIT	1N5400G	1N5401G	1N5402G	1N5404G	1N5406G	1N5407G	1N5408G
Typical Thermal Resistance	$R_{\theta J-A}$	°C/W	30						

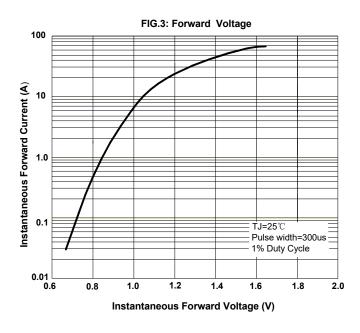
**■Ordering Information** (Example)

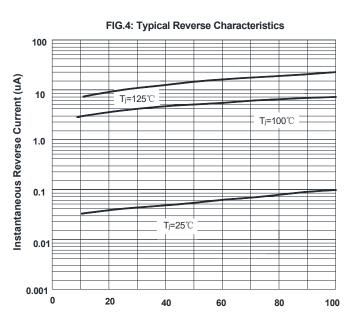
PREFERED P/N	PACKAGE CODE	UNIT WEIGHT(g)			OUTER CARTON QUANTITY(pcs)	DELIVERY MODE	
1N5400G~1N5408G	D1	Approximate 1.05	1250	1250	12500	Tape	
1N5400G~1N5408G	C1	Approximate 1.05	250	250	12500	Bulk	

## **■ Characteristics** (Typical)





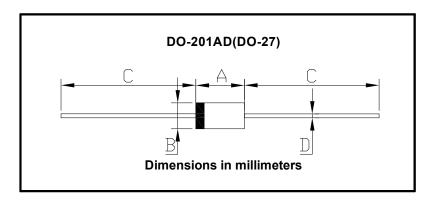






# 1N5400G THRU 1N5408G

## **■ Outline Dimensions**



DO-201AD(DO-27)						
Dim	Min	Max				
Α	8.50	9.50				
В	5.00	5.60				
С	25.4	1				
D	1.20	1.30				



## 1N5400G THRU 1N5408G

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